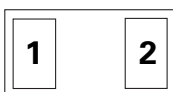


SP1005 Series 30pF 30kV Bidirectional Discrete TVS

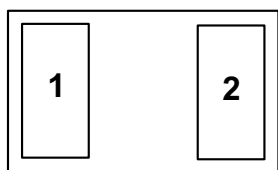


Pinout

0201 Flipchip

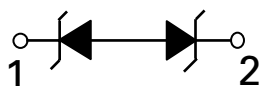


SOD882



(AEC-Q101 qualified)

Functional Block Diagram



Additional Information



Datasheet



Resources



Samples

Description

The SP1005 includes back-to-back Zener diodes fabricated in a proprietary silicon avalanche technology to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust diodes can safely absorb repetitive ESD strikes above the maximum level specified in the IEC61000-4-2 international standard (Level 4, ±8kV contact discharge) without performance degradation. The back-to-back configuration provides symmetrical ESD protection for data lines when AC signals are present.

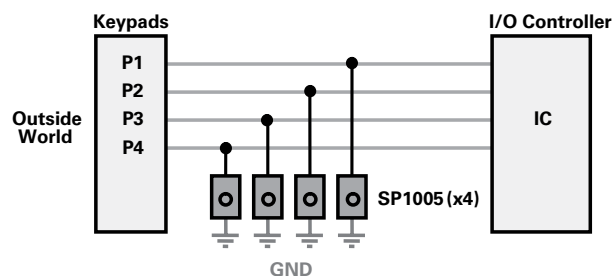
Features

- ESD, IEC61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC61000-4-4, 40A (5/50ns)
- Lightning, IEC61000-4-5, 10A (t_p=8/20µs)
- Low capacitance of 30pF (@ V_R=0V)
- Low leakage current of 0.1µA at 5V
- Space efficient 0201 and 0402 footprint
- AEC-Q101 qualified (SOD882 package)

Applications

- Mobile Phones
- Smart Phones
- Camcorders
- Portable Medical
- Digital Cameras
- MP3/PMP
- Portable Navigation Devices
- Tablets
- Point of Sale Terminals

Application Example



Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I _{PP}	Peak Current (t _p =8/20μs)	10.0 ¹	A
		8.0 ²	
T _{OP}	Operating Temperature	-40 to 125	°C
T _{STOR}	Storage Temperature	-55 to 150	°C

Notes:

1. "1" indicates SP1005-01WTG, while "2" indicates SP1005-01ETG

2. CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Thermal Information

Parameter	Rating	Units
Storage Temperature Range	-55 to 150	°C
Maximum Junction Temperature	150	°C
Maximum Lead Temperature (Soldering 20-40s)	260	°C

Electrical Characteristics (T_{OP}=25°C)

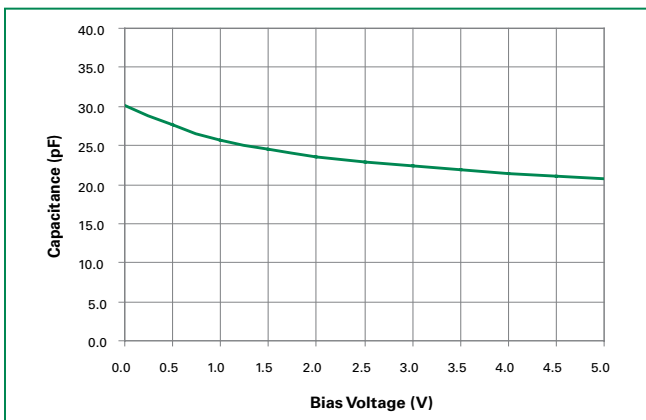
Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V _{RWM}				6.0	V
Breakdown Voltage	V _{BR}	I _R =1mA		8.5	9.5	V
Leakage Current	I _{LEAK}	V _R =5V with 1 pin at GND		0.1	0.5	μA
Clamp Voltage ¹	V _C	I _{PP} =1A, t _p =8/20μs, Fwd		9.3		V
		I _{PP} =2A, t _p =8/20μs, Fwd		10.0		V
		I _{PP} =10A, t _p =8/20μs, Fwd		15.6		V
Dynamic Resistance ²	R _{DYN}	TLP; t _p =100ns, I/O to GND		0.28		Ω
ESD Withstand Voltage ¹	V _{ESD}	IEC61000-4-2 (Contact Discharge)	±30			kV
		IEC61000-4-2 (Air Discharge)	±30			kV
Diode Capacitance ¹	C _D	Reverse Bias=0V		30		pF
		Reverse Bias=2.5V		23		pF

Notes:

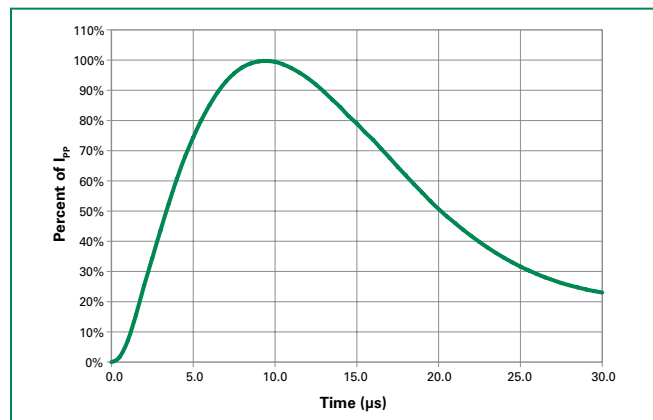
1. Parameter is guaranteed by design and/or device characterization.

2. Transmission Line Pulse (TLP) with 100ns width and 200ns rise time.

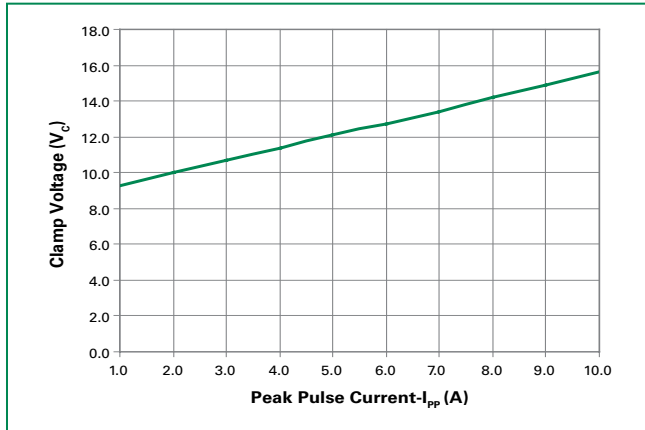
Capacitance vs. Reverse Bias



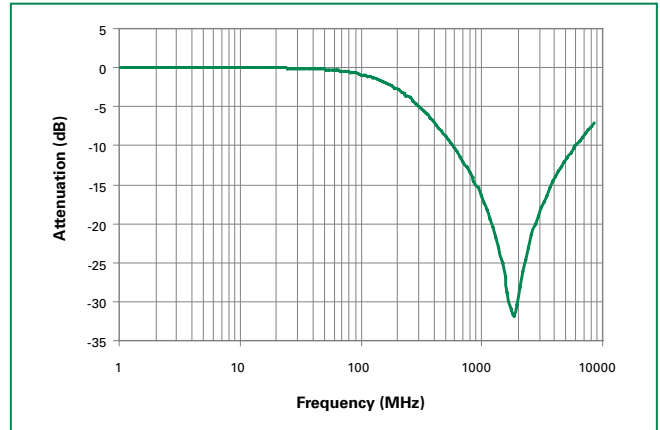
Pulse Waveform



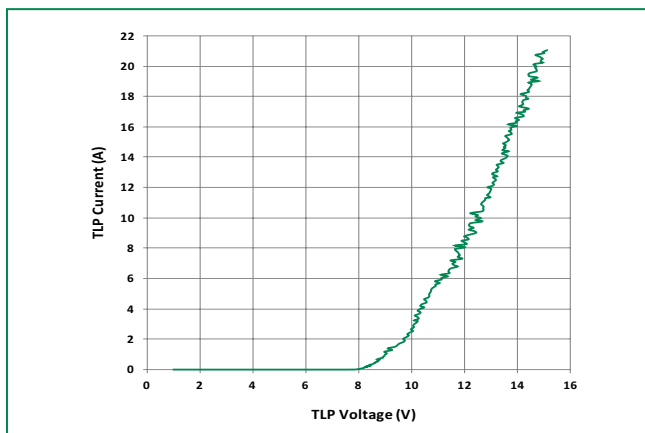
Clamping Voltage vs. I_{pp}



Insertion Loss (S21) I/O to GND



Transmission Line Pulsing (TLP) Plot



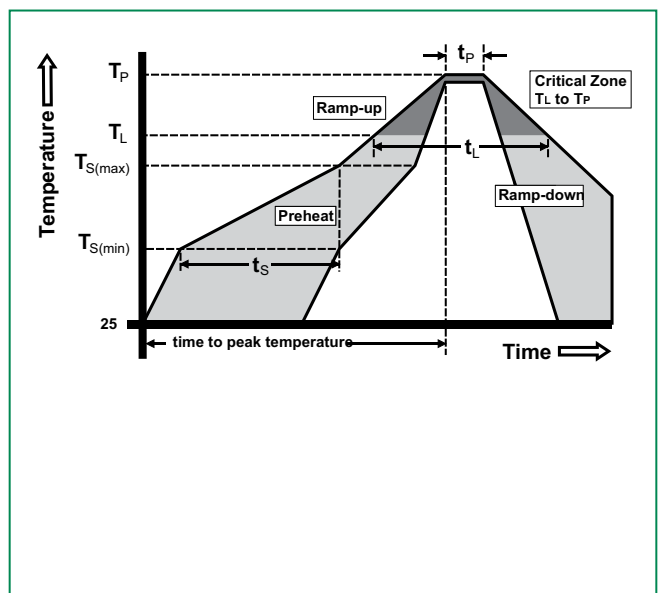
Product Characteristics of SOD-882 Package

Lead Plating	Pre-Plated Frame
Lead Material	Copper Alloy
Lead Coplanarity	0.0004 inches (0.102mm)
Substitute Material	Silicon
Body Material	Molded Epoxy
Flammability	UL 94 V-0

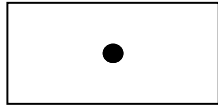
- Notes :
1. All dimensions are in millimeters
 2. Dimensions include solder plating.
 3. Dimensions are exclusive of mold flash & metal burr.
 4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
 5. Package surface matte finish VDI 11-13.

Soldering Parameters

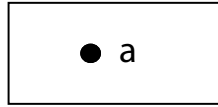
Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ($T_{s(min)}$)	150°C
	- Temperature Max ($T_{s(max)}$)	200°C
	- Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	- Temperature (T_L) (Liquidus)	217°C
	- Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C



Part Marking System

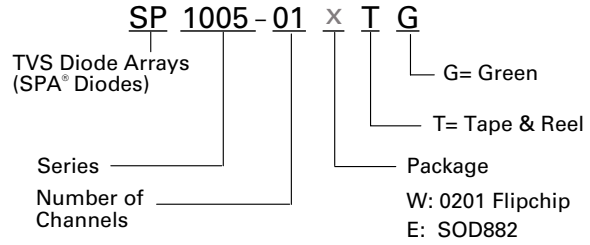


SP1005-01WTG



SP1005-01ETG

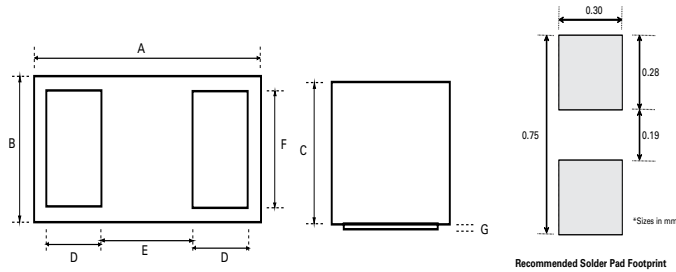
Part Numbering System



Ordering Information

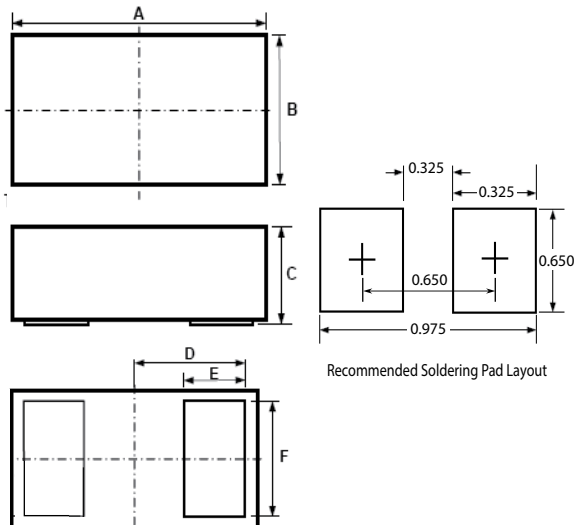
Part Number	Package	Marking	Min. Order Qty.
SP1005-01WTG	0201 Flipchip	•	10,000
SP1005-01ETG	SOD882	•a	10,000

Package Dimensions — 0201 Flipchip



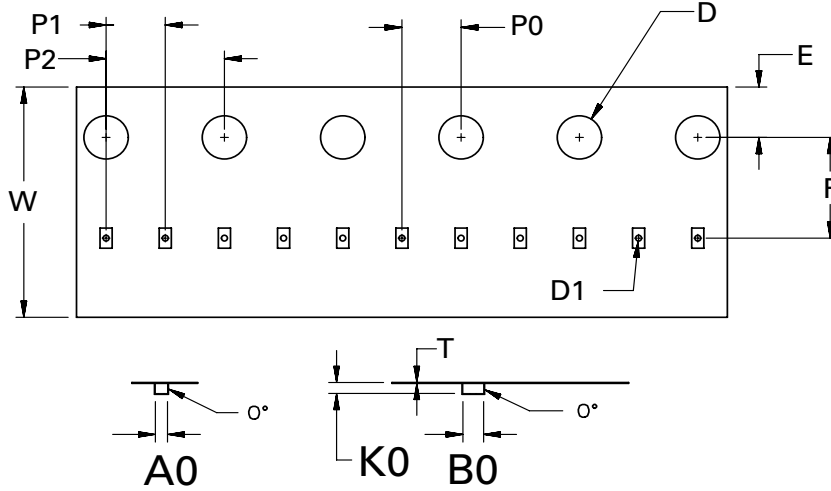
Symbol	0201 Flipchip					
	Millimeters			Inches		
	Min	Typ	Max	Min	Typ	Max
A	0.595	0.620	0.645	0.0234	0.0244	0.0254
B	0.295	0.320	0.345	0.0116	0.0126	0.0136
C	0.245	0.275	0.305	0.0096	0.0108	0.0120
D	0.145	0.150	0.155	0.0057	0.0059	0.0061
E	0.245	0.250	0.255	0.0096	0.0098	0.0100
F	0.245	0.250	0.255	0.0096	0.0098	0.0100
G	0.005	0.010	0.015	0.0002	0.0004	0.0006

Package Dimensions — SOD882



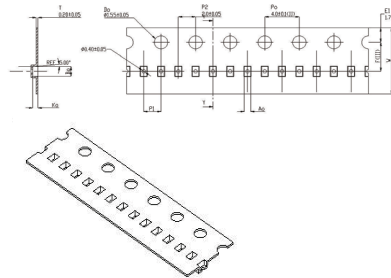
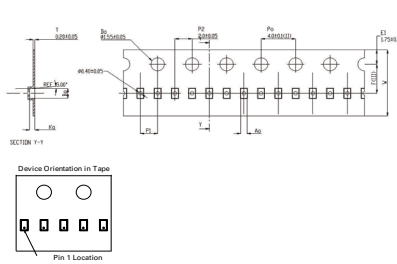
Symbol	Package	SOD882					
	JEDEC	MO-236					
		Millimeters			Inches		
		Min	Typ	Max	Min	Typ	Max
A		0.90	1.00	1.10	0.035	0.039	0.043
B		0.50	0.60	0.70	0.020	0.024	0.028
C		0.40	0.50	0.60	0.016	0.020	0.024
D		0.45			0.018		
E		0.20	0.25	0.35	0.008	0.010	0.012
F		0.45	0.50	0.55	0.018	0.020	0.022

Embossed Carrier Tape & Reel Specification – 0201 Flipchip



Symbol	Millimeters
A0	0.41±0.03
B0	0.70±0.03
D	∅ 1.50 + 0.10
D1	∅ 0.20 ± 0.05
E	1.75±0.10
F	3.50±0.05
K0	0.38±0.03
P0	2.00±0.05
P1	2.00±0.05
P2	4.00±0.10
W	8.00 + 0.30 -0.10
T	0.23±0.02

Embossed Carrier Tape & Reel Specification – SOD882



Symbol	Millimeters
A0	0.70±0.045
B0	1.10±0.045
K0	0.65±0.045
F	3.50±0.05
P1	2.00±0.10
W	8.00 + 0.30 -0.10